NSN 5961-01-112-5543

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Inclosure Material:

Plastic

Overall Length:

Between 0.360 inches and 0.410 inches

Overall Height:

Between 0.120 inches and 0.190 inches

Overall Width:

Between 0.280 inches and 0.320 inches

Mounting Facility Quantity:

1

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-202

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

80.0 drain to gate voltage and 80.0 drain to source voltage and 115.0 forward gate to source voltage

Current Rating Per Characteristic:

2.00 amperes drain current

Power Rating Per Characteristic:

12.5 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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